

Features

- AEC-Q100 Grade 2 temperature range (-40°C to 105°C). Grade 3 and 4 also available
- Any frequency between 1 MHz and 220 MHz, accurate to 6 decimal places. For frequency between 220 and 725 MHz, see SiT9387
- LVPECL, LVDS and HCSL output signaling types
- 0.23 ps RMS (typ) phase jitter (random, 12 kHz to 20 MHz)
- Frequency stability as low as ±10 ppm contact SiTime
- Industry-standard packages: 3.2 x 2.5, 7.0 x 5.0 mm.
 Contact SiTime for 5.0 x 3.2 mm package

Applications

- Automotive, and other high reliability electronics
- Infotainment systems, collision detection devices and in-vehicle 10/40/100 Gbps Ethernet



Electrical Characteristics

Table 1. Electrical Characteristics — Common to LVPECL, LVDS and HCSL

All Min and Max limits in the Electrical Characteristics tables are specified over temperature and rated operating voltage with standard output termination show in the termination diagrams. Typical values are at 25°C and nominal supply voltage.

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
			Free	quency Ran	ge		
Output Frequency Range	f	1	-	220	MHz	Accurate to 6 decimal places	
			Freq	uency Stabi	lity		
Frequency Stability		-10	-	+10	ppm	Inclusive of initial tolerance, operating temperature, rated	
		-20	-	+20	ppm	power supply voltage and load variations. Contact SiTime for ±10 ppm	
		-25	-	+25	ppm		
		-50	-	+50	ppm		
First Year Aging	F_1y	-	±1	-	ppm	At 25°C	
	•	r	Tem	perature Ra	nge		
		-20	-	+70	°C	AEC-Q100 Grade 4	
Operating Temperature Range	T_use	-40	-	+85	°C	AEC-Q100 Grade 3	
		-40	-	+105	°C	AEC-Q100 Grade 2	
			Su	pply Voltag	е		
	Vdd	2.97	3.3	3.63	V		
Supply Voltage		2.70	3.0	3.30	V		
Supply Voltage	vuu	2.52	2.8	3.08	V		
		2.25	2.5	2.75	V		
			Input	Characteris	tics		
Input Voltage High	VIH	70%	-	-	Vdd	Pin 1, OE	
Input Voltage Low	VIL	-	-	30%	Vdd	Pin 1, OE	
Input Pull-up Impedance	Z_in	-	100	-	kΩ	Pin 1, OE logic high or logic low	
			Outpu	It Character	istics		
Duty Cycle	DC	45	-	55	%		
			Startu	p and OE Ti	ming		
Start-up Time	T_start	-	-	3.0	ms	Measured from the time Vdd reaches its rated minimum value	
OE Enable/Disable Time	T_oe	-	-	3.8	μs	f = 156.25 MHz. Measured from the time OE pin reaches rated VIH and VIL to the time clock pins reach 90% of swing and high-Z. See Figure 6 and Figure 7	



Table 2. Electrical Characteristics – LVPECL

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
				nt Consump	otion	
Current Consumption	ldd	-	-	89	mA	Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V
OE Disable Supply Current	I_OE	-	-	58	mA	OE = Low
Output Disable Leakage Current	I_leak	-	0.15	-	μA	OE = Low
Maximum Output Current	I_driver	-	_	33	mA	Maximum average current drawn from OUT+ or OUT-
	•		Output	t Characteri	stics	
Output High Voltage	VOH	Vdd-1.15	-	Vdd-0.7	V	See Figure 2
Output Low Voltage	VOL	Vdd-2.0	-	Vdd-1.5	V	See Figure 2
Output Differential Voltage Swing	V_Swing	1.2	1.6	2.0	V	See Figure 3
Rise/Fall Time	Tr, Tf	-	225	310	ps	20% to 80%, see Figure 3
			Jitter -	7.0 x 5.0 pa	ckage	
RMS Period Jitter ^[1]	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	_	0.225	0.270	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40 to 85°C
		-	0.225	0.300	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -40 to 105°C
		-	0.1		ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels
			Jitter -	3.2 x 2.5 pa	ckage	
RMS Period Jitter ^[1]	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	_	0.225	0.275	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -20 to 70°C and -40 to 85° C
		_	0.225	0.340	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -40 to 105° C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels

Notes:

1. Measured according to JESD65B.



Table 3. Electrical Characteristics – LVDS

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
			Curre	nt Consump	otion	
Current Consumption	Idd	-	-	79	mA	Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V
OE Disable Supply Current	I_OE	-	-	58	mA	OE = Low
Output Disable Leakage Current	I_leak	-	0.15	-	μA	OE = Low
			Outpu	t Characteri	stics	
Differential Output Voltage	VOD	250	-	450	mV	See Figure 4
VOD Magnitude Change	ΔVOD	-	-	50	mV	See Figure 4
Offset Voltage	VOS	1.125	-	1.375	V	See Figure 4
VOS Magnitude Change	ΔVOS	-	-	50	mV	See Figure 4
Rise/Fall Time	Tr, Tf	-	400	515	ps	Measured with 2 pF capacitive loading to GND, 20% to 80%, see Figure 5
			Jitter -	7.0 x 5.0 pa	ckage	
RMS Period Jitter ^[2]	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	-	0.215	0.265	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40 to 85°C.
		-	0.215	0.300	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -40 to 105°C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels.
			Jitter -	3.2 x 2.5 pa	ckage	
RMS Period Jitter ^[2]	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	-	0.235	0.275	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40 to 85° C
		-	0.235	0.320	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -40 to 105°C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels

Notes:

2. Measured according to JESD65B.



Table 4. Electrical Characteristics – HCSL

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
T didilitici	Gynnson			nt Consum		Contraction
Current Consumption	ldd	_	_	92	mA	Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V
OE Disable Supply Current	I OE	_	-	58	mA	OE = Low
Output Disable Leakage Current	 I_leak	_	0.15	_	μA	OE = Low
Maximum Output Current	I_driver	_	_	35	mA	Maximum average current drawn from OUT+ or OUT-
			Outpu	t Characteri	stics	-
Output High Voltage	VOH	0.60	-	0.90	V	See Figure 2
Output Low Voltage	VOL	-0.05	-	0.08	V	See Figure 2
Output Differential Voltage Swing	V_Swing	1.2	1.4	1.80	V	See Figure 3
Rise/Fall Time	Tr, Tf	-	360	495	ps	Measured with 2 pF capacitive loading to GND, 20% to 80%, see Figure 3
			Jitter -	7.0 x 5.0 pa	ckage	
RMS Period Jitter ^[3]	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	-	0.220	0.270	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -20 to 70°C and -40 to 85°C.
		-	0.220	0.300	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -40 to 105° C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels.
			Jitter -	3.2 x 2.5 pa	ckage	
RMS Period Jitter ^[3]	T_jitt	-	1.0	1.6	ps	f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V
RMS Phase Jitter (random)	T_phj	-	0.230	0.275	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40 to 85°C.
		-	0.230	0.340	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range -40 to 105° C
		-	0.1	-	ps	f = 156.25 or 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, includes spurs, all Vdd levels.

Notes:

3. Measured according to JESD65B.



Table 5. Pin Description

Pin	Мар	Functionality				
1	OE/NC	Output Enable (OE)	H ^[5] : specified frequency output L: output is high impedance			
	Non Connect (NC)		H or L or Open: No effect on output frequency or other device functions			
2	NC	NA	No Connect; Leave it floating or connect to GND for better heat dissipation			
3	GND	Power	Vdd Power Supply Ground			
4	OUT+	Output	Oscillator output			
5	OUT-	Output Complementary oscillator output				
64	Vdd	Power				

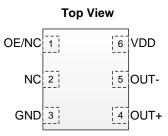


Figure 1. Pin Assignments

Notes:

- 5. In OE mode, a pull-up resistor of 10 k Ω or less is recommended if pin 1 is not externally driven.
- 6. A capacitor of value 0.1 μF or higher between Vdd and GND is required. An additional 10 μF capacitor between Vdd and GND is required for the best phase jitter performance.

Table 6. Absolute Maximum Ratings

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

			5
Parameter	Min.	Max.	Unit
Vdd	-0.5	4.0	V
VIH		Vdd + 0.3V	V
VIL	-0.3		V
Storage Temperature	-65	150	°C
Maximum Junction Temperature		130	°C
Soldering Temperature (follow standard Pb-free soldering guidelines)		260	°C

Table 7. Thermal Considerations^[7]

Package	$ heta_{ extsf{JA}}$, 4 Layer Board (°C/W)	θյ₀, Bottom (°C/W)
3225, 6-pin	80	30
7050, 6-pin	52	19

Notes:

7. Refer to JESD51 for θ_{JA} and θ_{JC} definitions, and reference layout used to determine the θ_{JA} and θ_{JC} values in the above table.

Table 8. Maximum Operating Junction Temperature^[8]

Max Operating Temperature (ambient)	Maximum Operating Junction Temperature
70°C	95°C
85°C	110°C
105°C	130°C

Notes:

8. Datasheet specifications are not guaranteed if junction temperature exceeds the maximum operating junction temperature.

Table 9. Environmental Compliance

Parameter	Test Conditions	Value	Unit
Mechanical Shock Resistance	MIL-STD-883F, Method 2002	10,000	g
Mechanical Vibration Resistance	MIL-STD-883F, Method 2007	70	g
Soldering Temperature (follow standard Pb free soldering guidelines)	MIL-STD-883F, Method 2003	260	°C
Moisture Sensitivity Level	MSL1 @ 260°C		
Electrostatic Discharge (HBM)	HBM, JESD22-A114	2,000	V
Charge-Device Model ESD Protection	JESD220C101	750	V
Latch-up Tolerance	JESD	78 Compliant	



Waveform Diagrams (continued)

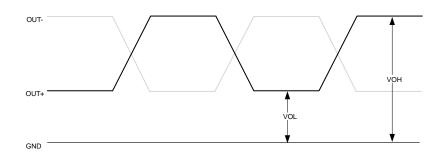


Figure 2. LVPECL/HCSL Voltage Levels per Differential Pin (OUT+/OUT-)

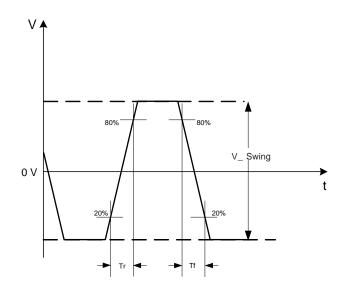


Figure 3. LVPECL/HCSL Voltage Levels across Differential Pair



Waveform Diagrams (continued)

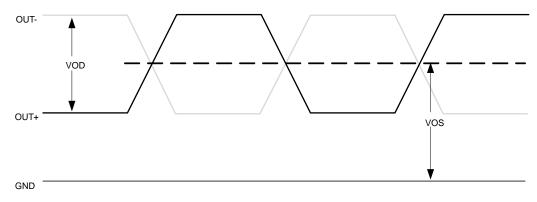
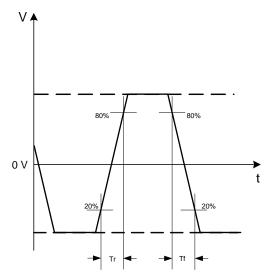
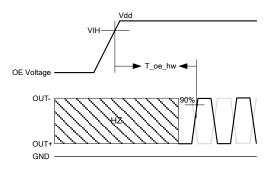


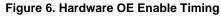
Figure 4. LVDS Voltage Levels per Differential Pin (OUT+/OUT-)





Timing Diagrams





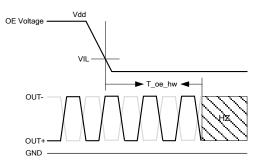
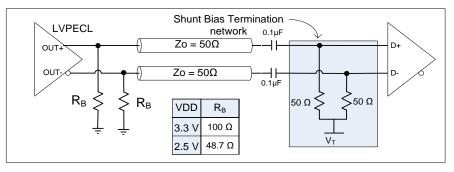


Figure 7. Hardware OE Disable Timing



Termination Diagrams

LVPECL





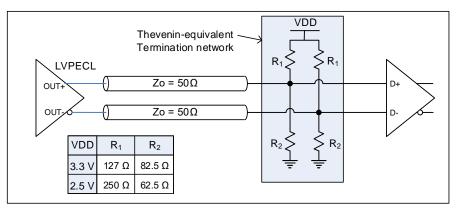


Figure 9. LVPECL DC-coupled load termination with Thevenin equivalent network

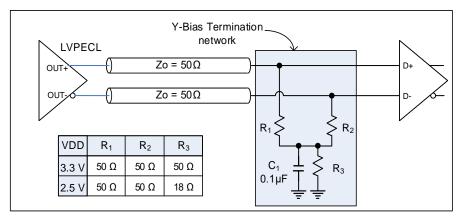
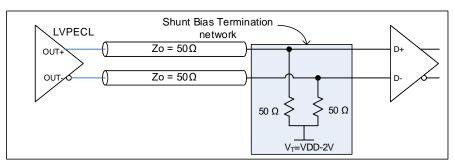


Figure 10. LVPECL with Y-Bias termination







Termination Diagrams (continued)

LVDS

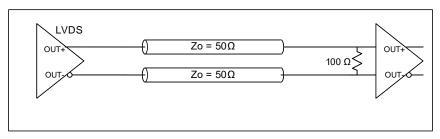


Figure 12. LVDS single DC termination at the load

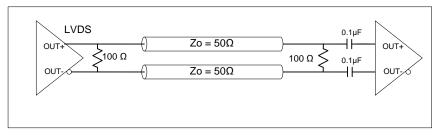


Figure 13. LVDS double AC termination with capacitor close to the load

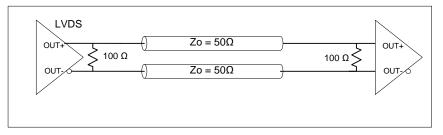


Figure 14. LVDS double DC termination

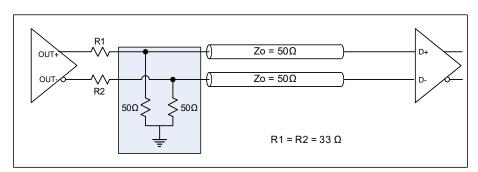
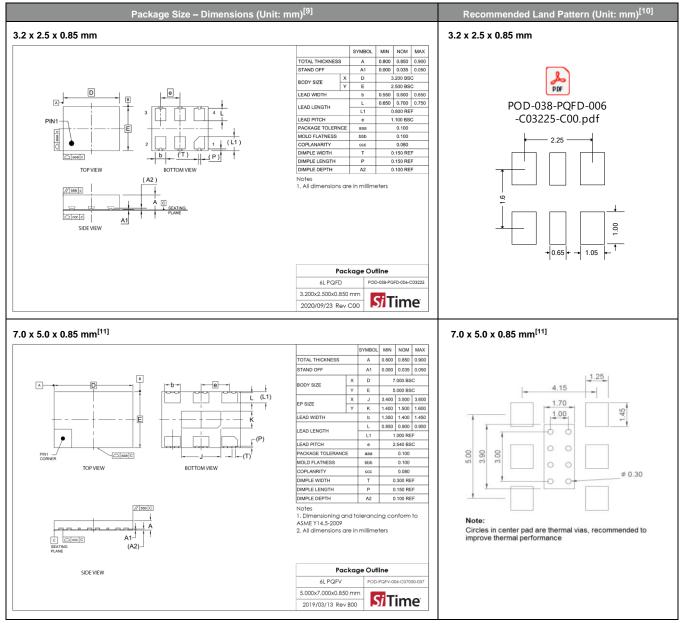


Figure 15. HCSL interface termination

HCSL



Dimensions and Patterns

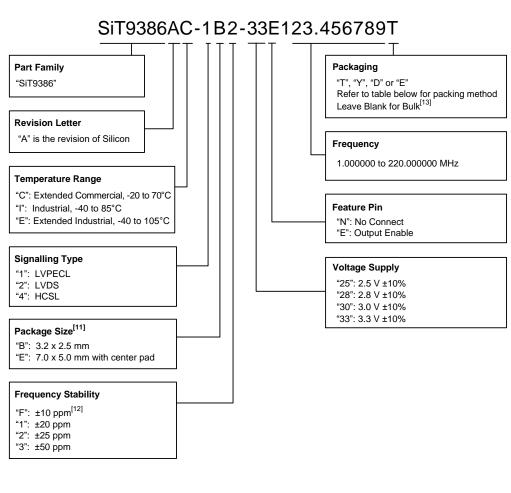


Notes:

- 9. Top Marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
- 10. A capacitor of value 0.1 µF or higher between Vdd and GND is required. An additional 10 µF capacitor between Vdd and GND is required for the best phase jitter performance
- 11. The center pad has no electrical function. Soldering down the center pad to the GND is recommended for best thermal dissipation, but is optional.



Ordering Information



Notes:

12. Contact SiTime for 5.0 x 3.2 mm package.

13. Contact SiTime for ±10 ppm option.

14. Bulk is available for sampling only.

Table 10. Ordering Codes for Supported Tape & Reel Packing Method

Device Size (mm x mm)	8 mm T&R (3ku)	8 mm T&R (1ku)	12 mm T&R (3ku)	12 mm T&R (1ku)	16 mm T&R (3ku)	16 mm T&R (1ku)
7.0 x 5.0	—	—	—	—	Т	Y
3.2 x 2.5	D	E			—	—



Table 11. Additional Information

Document	Description	Download Link
ECCN #: EAR99	Five character designation used on the commerce Control List (CCL) to identify dual use items for export control purposes.	—
Part number Generator	Tool used to create the part number based on desired features.	https://www.sitime.com/part-number-generator
Manufacturing Notes	Tape & Reel dimension, reflow profile and other manufacturing related info	https://www.sitime.com/sites/default/files/gated/Manufacturing-Notes-for-SiTime-Products.pdf
Qualification Reports	RoHS report, reliability reports, composition reports	http://www.sitime.com/support/quality-and-reliability
Performance Reports	Additional performance data such as phase noise, current consumption and jitter for selected frequencies	http://www.sitime.com/support/performance-measurement-report
Termination Techniques	Termination design recommendations	http://www.sitime.com/support/application-notes
Layout Techniques	Layout recommendations	http://www.sitime.com/support/application-notes

Table 12. Revision History

Revision	Release Date	Change Summary
0.1	8-Mar-2021	Initial draft
0.87	6-Nov-2017	Updated package drawings Corrected tape/reel ordering information Updated Electrical Characteristics based on characterization Included max numbers for IPJ Added additional information table Corrected formatting issues Increased temperature range from 95°C to 105°C Removed ±10 ppm options for automotive and industrial temperature ranges Changed ±20 ppm to "contact SiTime" Updated termination diagrams Lower mechanical shock from 20,000 to 10,000 g
0.90	24-Nov-2017	Ordering information updates and page layout changes
1.0	15-Mar-2019	Updated Electrical Characteristics tables Updated waveform diagrams Added OE enable/disable timing diagrams Updated package dimensions Added an AEC-Q100 Grade 4 temperature option Updated the ordering information
1.01	9-Mar-2021	Updated L1 and Dimple Width package dimensions for 3.2 x 2.5 mm package Updated hyperlinks and changed rev table date format

SiTime Corporation, 5451 Patrick Henry Drive, Santa Clara, CA 95054, USA | Phone: +1-408-328-4400 | Fax: +1-408-328-4439

© SiTime Corporation 2017-2021. The information contained herein is subject to change at any time without notice. SiTime assumes no responsibility or liability for any loss, damage or defect of a Product which is caused in whole or in part by (i) use of any circuitry other than circuitry embodied in a SiTime product, (ii) misuse or abuse including static discharge, neglect or accident, (iii) unauthorized modification or repairs which have been soldered or altered during assembly and are not capable of being tested by SiTime under its normal test conditions, or (iv) improper installation, storage, handling, warehousing or transportation, or (v) being subjected to unusual physical, thermal, or electrical stress.

Disclaimer: SiTime makes no warranty of any kind, express or implied, with regard to this material, and specifically disclaims any and all express or implied warranties, either in fact or by operation of law, statutory or otherwise, including the implied warranties of merchantability and fitness for use or a particular purpose, and any implied warranty arising from course of dealing or usage of trade, as well as any common-law duties relating to accuracy or lack of negligence, with respect to this material, any SiTime product and any product documentation. Products sold by SiTime are not suitable or intended to be used in a life support application or component, to operate nuclear facilities, or in other mission critical applications where human life may be involved or at stake. All sales are made conditioned upon compliance with the critical uses policy set forth below.

CRITICAL USE EXCLUSION POLICY

BUYER AGREES NOT TO USE SITIME'S PRODUCTS FOR ANY APPLICATION OR IN ANY COMPONENTS USED IN LIFE SUPPORT DEVICES OR TO OPERATE NUCLEAR FACILITIES OR FOR USE IN OTHER MISSION-CRITICAL APPLICATIONS OR COMPONENTS WHERE HUMAN LIFE OR PROPERTY MAY BE AT STAKE.

SiTime owns all rights, title and interest to the intellectual property related to SiTime's products, including any software, firmware, copyright, patent, or trademark. The sale of SiTime products does not convey or imply any license under patent or other rights. SiTime retains the copyright and trademark rights in all documents, catalogs and plans supplied pursuant to or ancillary to the sale of products or services by SiTime. Unless otherwise agreed to in writing by SiTime, any reproduction, modification, translation, compilation, or representation of this material shall be strictly prohibited.